PATENT APPLICATION

THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

TAMATSUKA

ATTN: Application Branch

Application No.: 09/868,901

3,901 Attorney Dkt. No

Attorney Dkt. No.: 107242-00019

Filed: July 9, 2001

For: "SILICOI

"SILICON SINGLE CRYSTAL WAFER AND MANUFACTURING PROCESS

THEREFOR".

REQUEST FOR CORRECTED FILING RECEIPT

Commissioner for Patents Washington, D.C. 20231

September 11, 2001

Sir:

A corrected filing receipt is hereby requested in view of the errors which appear in the original filing receipt. For the convenience of the Patent and Trademark Office, attached is a photocopy of the original filing receipt on which the errors have been noted in red.

Please charge any deficiency or credit any overpayment with respect to this paper to Deposit Account No. 01-2300.

Respectfully submitted,

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CONFIRMATION NO. 1242

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FILING RECEIPT

Date Mailed: 08/14/2001

Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Customer Service Center. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

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Title

Silicon single crystal wafer and production method therefor

Silicon Single Crystal water and Manufacturing Process Theref

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